NSN 5961-00-419-7518

Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Glass
Overall Length:
0.160 inches
Геrminal Length:
1.000 inches
Overall Diameter:
0.075 inches
Mounting Method:
Геrminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 reverse voltage, peak
Current Rating Per Characteristic:
1.00 amperes repetitive peak forward current
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Jnit Of Measure:
-
Demilitarization:
No
-iia:

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